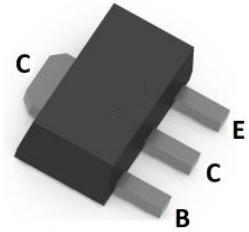
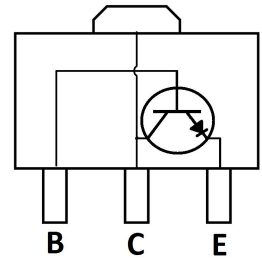


**BIPOLAR TRANSISTOR (NPN)**
**FEATURES**

- Large Collector Power Dissipation and Current
- Low Collector-Emitter Saturation Voltage
- Surface Mount device


**SOT-89**

**MECHANICAL DATA**

- Case: SOT-89
- Case Material: Molded Plastic. UL flammability
- Classification Rating: 94V-0
- Weight: 0.055 grams (approximate)

**MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)**

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CB0</sub>	40	V
Collector-Emitter Voltage	V <sub>CEO</sub>	20	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Collector Current	I <sub>C</sub>	5	A
Collector Power Dissipation	P <sub>C</sub>	750	mW
Thermal Resistance From Junction To Ambient	R <sub>θJA</sub>	167	°C/W
Junction Temperature	T <sub>J</sub>	150	°C
Storage Temperature	T <sub>STG</sub>	-55 ~+150	°C

**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise specified)**

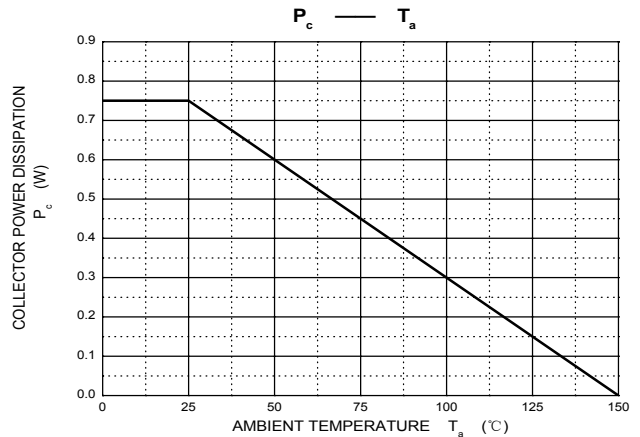
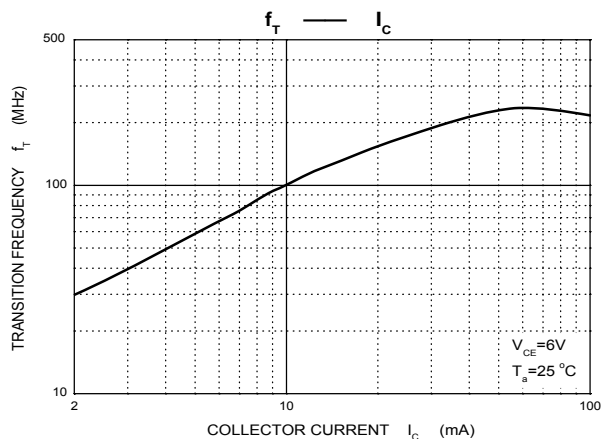
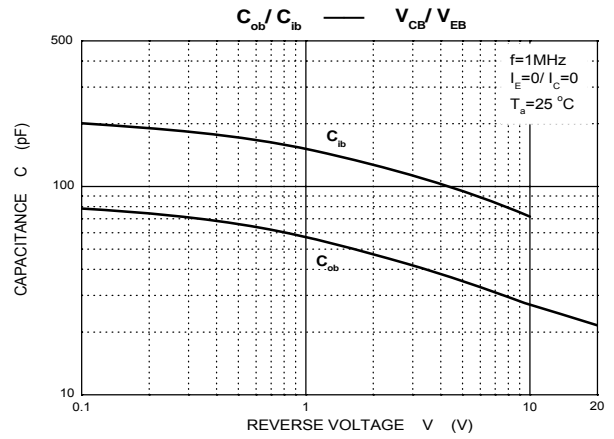
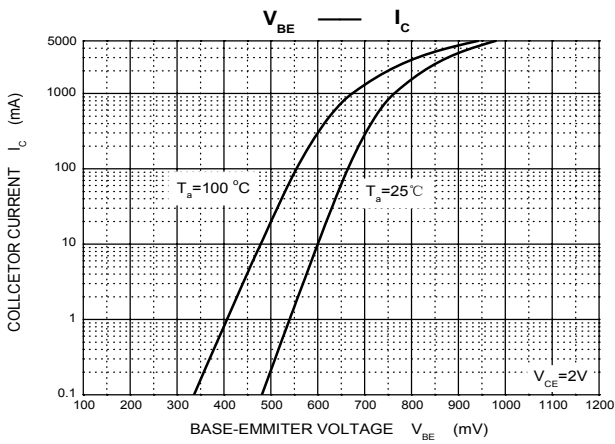
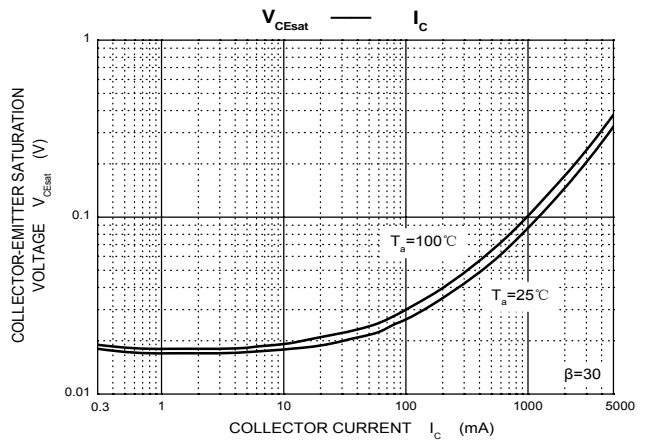
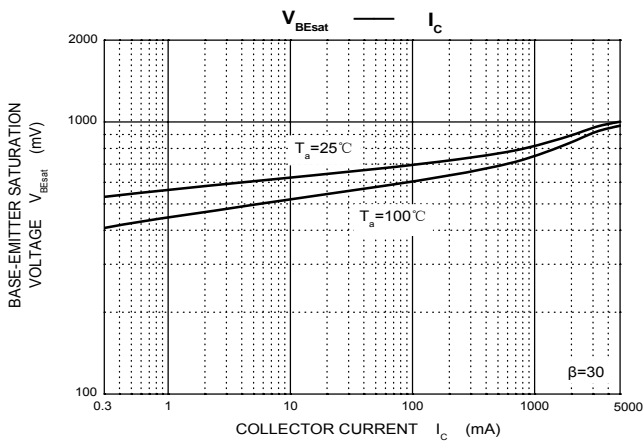
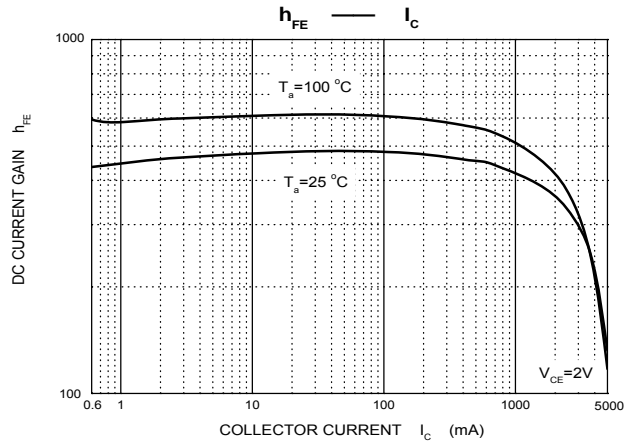
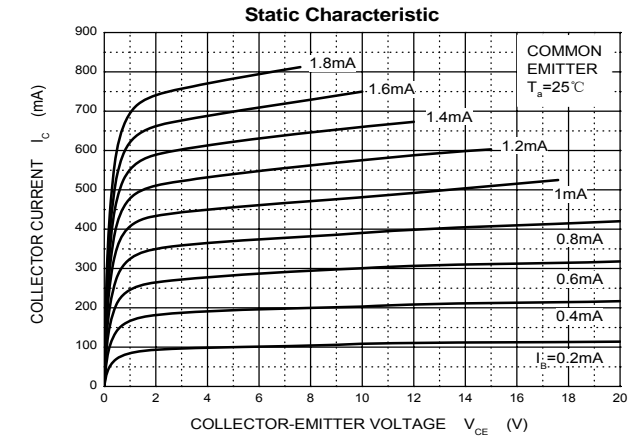
Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	40			V	I <sub>C</sub> =100uA, I <sub>E</sub> =0
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	20			V	I <sub>C</sub> =1mA, I <sub>B</sub> =0
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	7			V	I <sub>E</sub> =10uA, I <sub>C</sub> =0
Collector cut-off current	I <sub>CB0</sub>			0.1	uA	V <sub>CB</sub> =10V, I <sub>E</sub> =0
Emitter cut-off current	I <sub>EBO</sub>			0.1	uA	V <sub>EB</sub> =7V, I <sub>C</sub> =0
DC current gain	h <sub>FE1</sub>		200			V <sub>CE</sub> =2V, I <sub>C</sub> =1mA
	h <sub>FE2</sub>	230		800		V <sub>CE</sub> =2V, I <sub>C</sub> =500mA
	h <sub>FE3</sub>	150				V <sub>CE</sub> =2V, I <sub>C</sub> =2A
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>			1	V	I <sub>C</sub> =3A, I <sub>B</sub> =100mA
Transition frequency	f <sub>T</sub>		150		MHz	V <sub>CE</sub> =6V, I <sub>C</sub> =50mA, f=200MHz
Collector output capacitance	C <sub>ob</sub>			50	pF	V <sub>CB</sub> =20V, I <sub>E</sub> =0, f=1MHz

**CLASSIFICATION OF h<sub>FE</sub>**

Rank	Q	R	S
Range	230-380	340-600	560-800
Marking	D965		

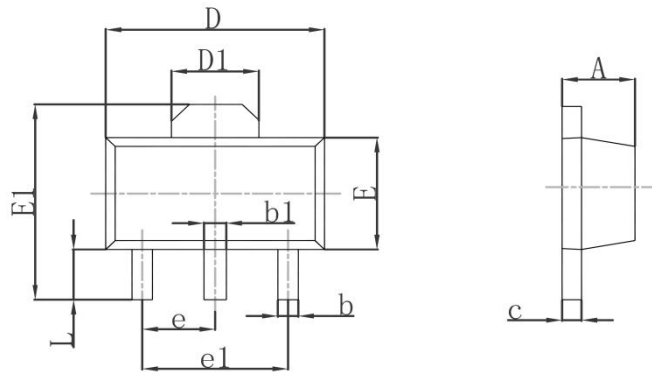
**BIPOLAR TRANSISTOR (NPN)**

**Typical Characteristics**



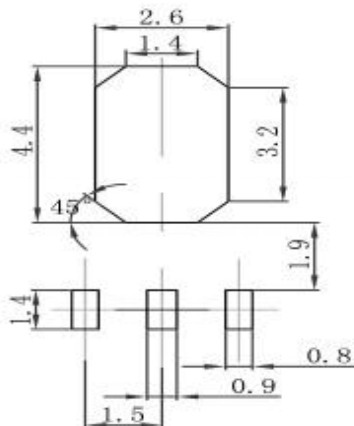
**BIPOlar TRANSISTOR (NPN)**

**SOT-89 Package Outline Dimensions**



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.400	0.580	0.016	0.023
c	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550REF		0.061REF	
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500TYP		0.060TYP	
e1	3.000TYP		0.118TYP	
L	0.900	1.200	0.035	0.047

**SOT-89 Suggested Pad Layout**



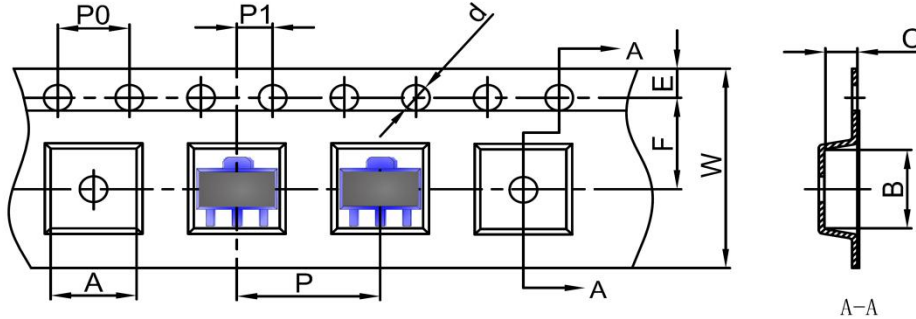
**Note:**

1. Controlling dimension: in millimeters
2. General tolerance:  $\pm 0.05\text{mm}$
3. The pad layout is for reference purposes only

**BIPOLAR TRANSISTOR (NPN)**

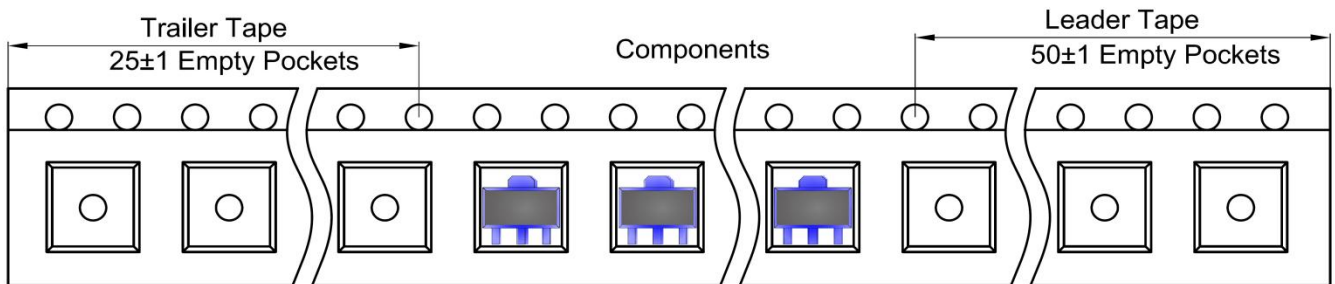
**SOT-89 Tape and Reel**

**SOT-89 Embossed Carrier Tape**

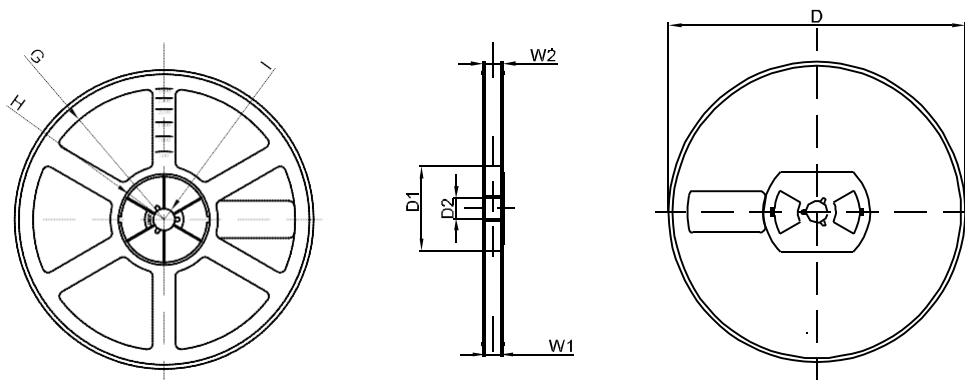


DIMENSIONS ARE IN MILLIMETER										
TYPE	A	B	C	d	E	F	P0	P	P1	W
SOT-89	4.85	4.45	1.85	Ø1.50	1.75	5.50	4.00	8.00	2.00	12.00
TOLERANCE	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1

**SOT-89 Tape Leader and Trailer**



**SOT-89 Reel**



DIMENSIONS ARE IN MILLIMETER								
REEL OPTION	D	D1	D2	G	H	I	W1	W2
7" DIA	Ø178	54.40	13.00	R78	R25.60	R6.50	13.20	16.50
TOLERANCE	±2	±1	±1	±1	±1	±1	±1	±1